



N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
$V_{DS}(V)$ $R_{DS(on)}(\Omega)$		I _D (A)			
30	0.00525 at V _{GS} = 10 V	20			
	0.007 at V _{GS} = 4.5 V	17			

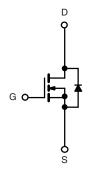
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET
- Optimized for "Low Side" Synchronous Rectifier Operation
- 100 % R_g Tested

ROHS COMPLIANT HALOGEN FREE Available

APPLICATIONS

- DC/DC Converters
- · Synchronous Rectifiers



N-Channel MOSFET

		SO-8		
s	1		8	D
S	2		7	D
S	3		6	D
G	4		5	D
		Top View	ı	

Ordering Information: Si4858DY-T1-E3 (Lead (Pb)-free)

Si4858DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS $T_A = 25 ^{\circ}C$, unless Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	- I _D	20	13	Δ
	T _A = 70 °C		15	10	
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	60		Α
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.3	
Maximum Power Dissipation ^a	T _A = 25 °C	В	3.5	1.6	W
	T _A = 70 °C	P_{D}	2.2	1	
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana baratian ta Ambianta	t ≤ 10 s	- R _{thJA}	29	35	°C/W
Maximum Junction-to-Ambient ^a	Steady State		67	80	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	13	16	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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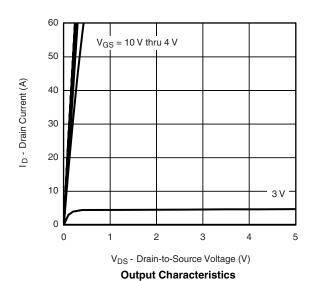
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0			٧		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zero Gate Voltage Drain Current		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$			1	μΑ		
	I _{DSS}				5			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 20 A	0.0040 0.		0.00525	Ω		
		V _{GS} = 4.5 V, I _D = 19 A 0.0055		0.0055	0.007			
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		90		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.75	1.1	V		
Dynamic ^b								
Total Gate Charge	Q_g			30.5	40			
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		13.5		nC		
Gate-Drain Charge	Q_{gd}			9.5				
Gate Resistance	R_g		0.5	1.4	2.4	Ω		
Turn-On Delay Time	t _{d(on)}			21	35			
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		10	20			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		83	130	ns		
Fall Time	t _f			27	45			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dI/dt = 100 A/μs		50	80			

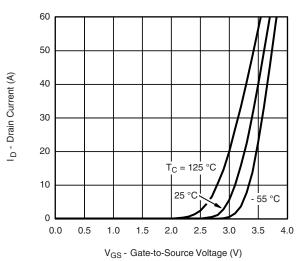
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



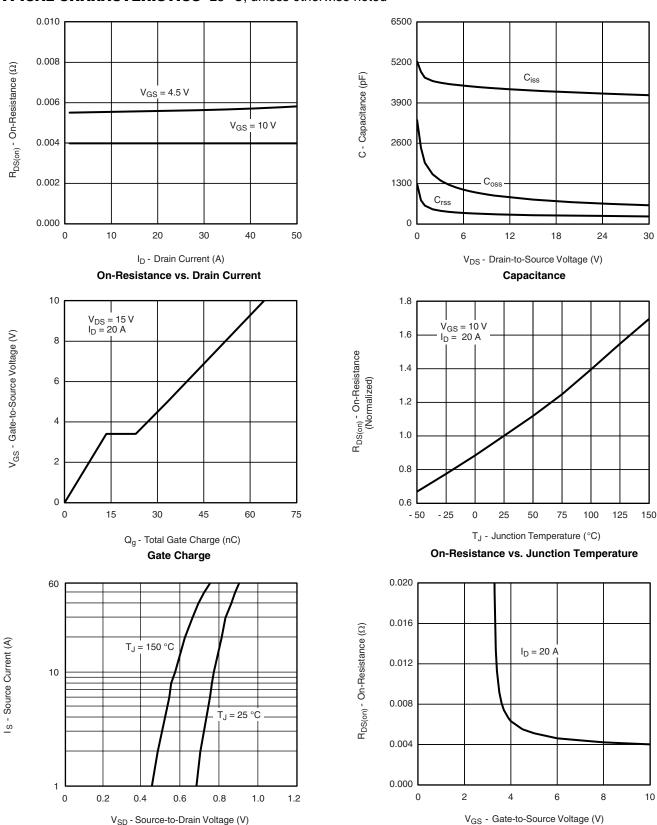








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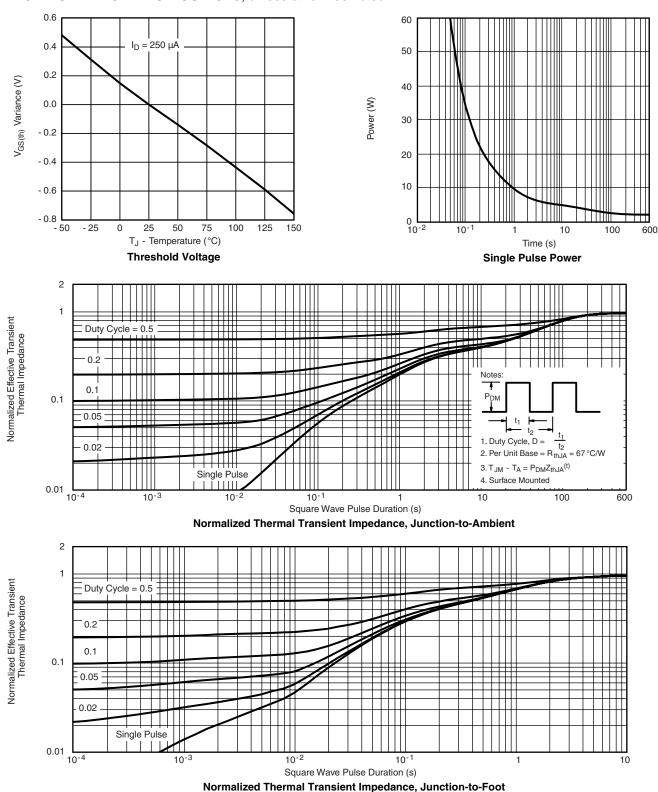
Source-Drain Diode Forward Voltage

On-Resistance vs. Gate-to-Source Voltage

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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